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overview: Facet-dependent metal oxide An

semiconductor gas sensors

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**Abstract** 

Metal oxide semiconductor (MOS) gas sensors possess extensive applications due to

their high sensitivity, low cost, and simplicity. To boost their excellent sensing

performance and meet the growing demand for applications, a series of strategies

have been developed, such as the surface morphology engineering and function

manipulation. Recently, the controlled morphology with exposed high-energy facets

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